# Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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# RJL5012DPP

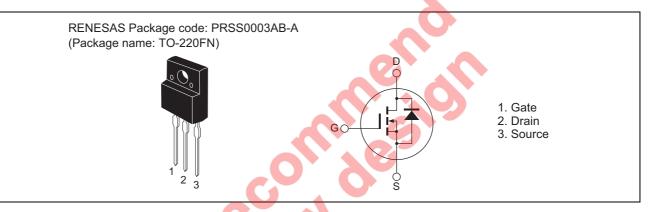
Silicon N Channel MOS FET High Speed Power Switching

> REJ03G1746-0200 Rev.2.00 Mar 05, 2009

### Features

- Built-in fast recovery diode
- Low on-resistance
- Low leakage current
- High speed switching

### Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item 💊 🚺	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	500	V
Gate to source voltage	V <sub>GSS</sub>	±30	V
Drain current	ID <sup>Note4</sup>	12	А
Drain peak current	Note1 D (pulse)	36	А
Body-drain diode reverse drain current	I <sub>DR</sub>	12	А
Body-drain diode reverse drain peak current	Note1 DR (pulse)	36	А
Avalanche current	I <sub>AP</sub> <sup>Note3</sup>	3	А
Avalanche energy	E <sub>AR</sub> <sup>Note3</sup>	0.5	mJ
Channel dissipation	Pch Note2	30	W
Channel to case thermal impedance	θch-c	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

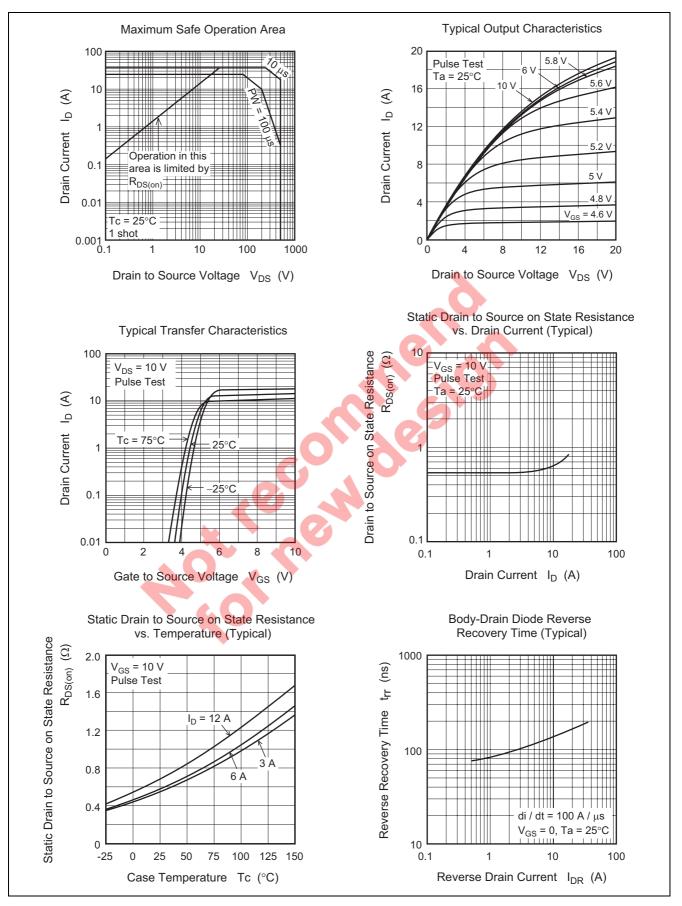
Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

- 2. Value at Tc =  $25^{\circ}$ C
- 3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C
- 4. Limited by maximum safe operation area

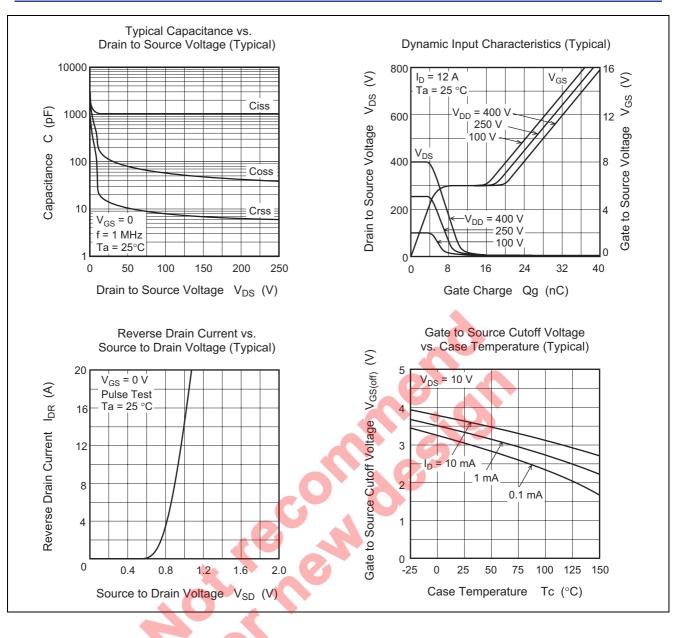
### **Electrical Characteristics**

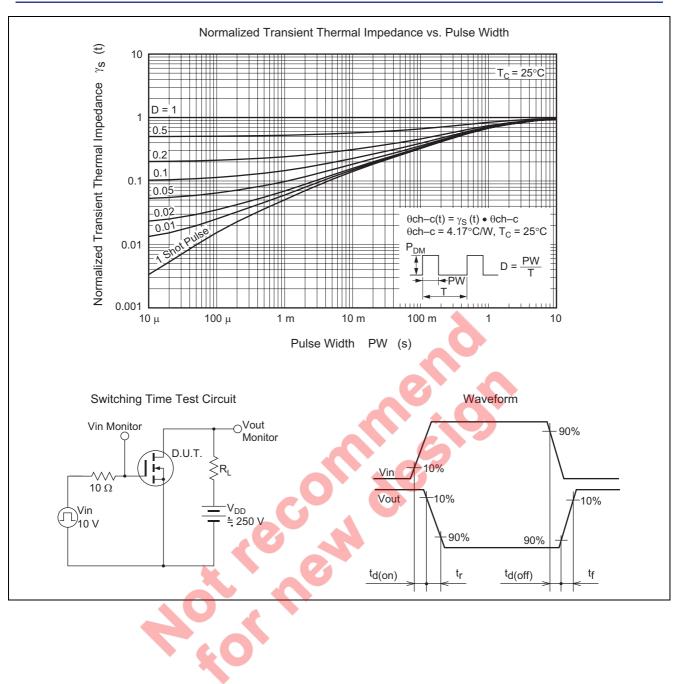
14						$(Ta = 25^{\circ}C)$
ltem	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	500		—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	—	—	10	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS}$ = ±30 V, $V_{DS}$ = 0
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	0.56	0.70	Ω	$I_D = 6 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$
Input capacitance	Ciss	_	1050		pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	115		pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	14		pF	f = 1 MHz
Turn-on delay time	t <sub>d(on)</sub>	_	27		ns	I <sub>D</sub> = 6 A
Rise time	tr		22		ns	V <sub>GS</sub> = 10 V
Turn-off delay time	t <sub>d(off)</sub>	_	78	—	ns	$R_L = 41.7 \ \Omega$
Fall time	t <sub>f</sub>	_	15	—	ns	Rg = 10 Ω
Total gate charge	Qg	_	27.8	—	nC	V <sub>DD</sub> = 400 V
Gate to source charge	Qgs		4.9	_	nC	$V_{GS}$ = 10 V
Gate to drain charge	Qgd		14.4		nC	I <sub>D</sub> = 12 A
Body-drain diode forward voltage	V <sub>DF</sub>	_	0.96	1.60	V	$I_F = 12 \text{ A}, V_{GS} = 0^{\text{Note5}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	140	-	ns	I <sub>F</sub> = 12 A, V <sub>GS</sub> = 0 di <sub>F</sub> /dt = 100 A/μs
Body-drain diode forward voltage Body-drain diode reverse recovery time Notes: 5. Pulse test	(0)	0	6	3		

### **Main Characteristics**

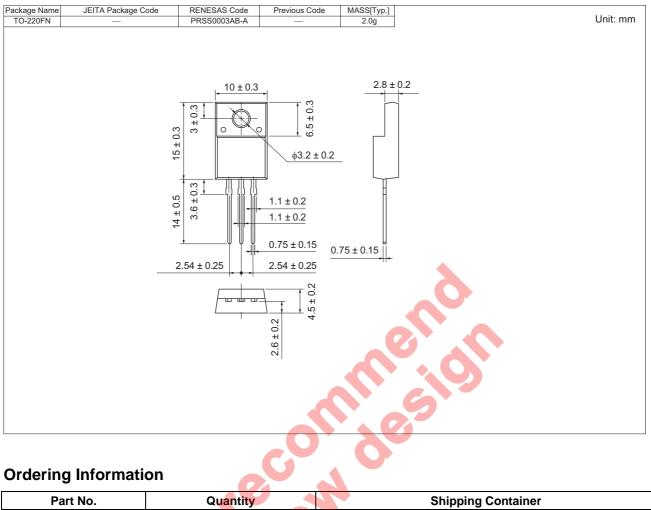


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### **Package Dimensions**



Part No.	Quantity	Shipping Container
RJL5012DPP-00-T2	1050 pcs	Box (Tube)
-		

2.0

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